



JLE05ULS9-2

1-Line Uni-directional High Power TVS Diode

Jialan-Microelectronics

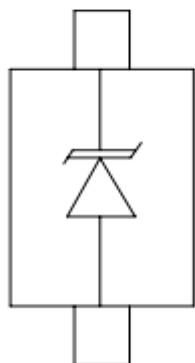
Description

The JLE05ULS9-2 is an uni-directional TVS diode, utilizing leading monolithic silicon technology to provide fast response time and low ESD clamping voltage, making this device an ideal solution for protecting voltage sensitive data and power line. The JLE05ULS9-2 complies with the IEC 61000-4-2 (ESD) with $\pm 30\text{kV}$ air and $\pm 30\text{kV}$ contact discharge. It is assembled into an ultra-small lead-free SOD-923 package. The small size and high ESD surge protection make JLE05ULS9-2 an ideal choice to protect cell phone, digital cameras, audio players and many other portable applications.

Features

- * 100W peak pulse power (8/20 μs)
- * Low leakage:nA level
- * Operating voltage: 5V
- * Ultra low clamping voltage
- * One power line protects
- * Complies with following standards:
 - IEC 61000-4-2 (ESD) immunity test
 - Air discharge: $\pm 30\text{kV}$
 - Contact discharge: $\pm 30\text{kV}$
 - IEC61000-4-5 (Lightning) 8A (8/20 μs)
- * RoHS Compliant
- * Package: SOD-923

Circuit Diagram



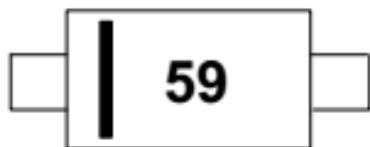
SOD-923 (Top View)

Circuit and Pin Schematic

Applications

- * Fast-charge battery chargers
- * Power management system
- * Cellular Handsets and Accessories
- * Personal Digital Assistants
- * Notebooks and Handhelds
- * Portable Instrumentation
- * Digital Cameras

Marking Diagram



Transparent top view

59:Device Marking Code

Ordering Information

Part Number	Packaging	Reel Size
JLE05ULS9 -2	8000/Tape & Reel	7 inch



JLE05ULS9-2

Absolute Maximum Ratings ($T_A=25^\circ\text{C}$ unless otherwise specified)

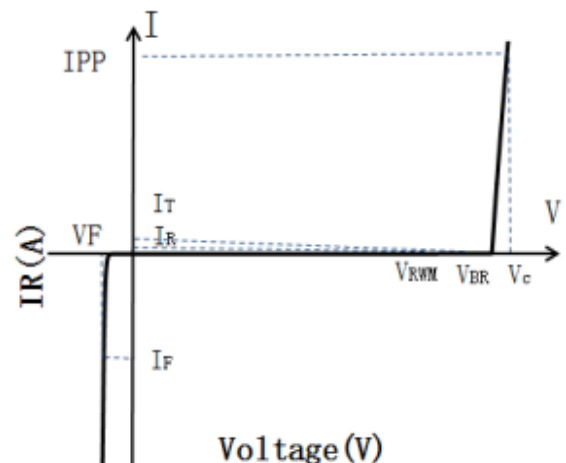
Parameter	Symbol	Value	Unit
Peak Pulse Power (8/20 μs)	Ppk	100	W
Peak Pulse Current (8/20 μs)	IPP	8	A
ESD per IEC 61000-4-2 (Air)	VESD	± 30	kV
ESD per IEC 61000-4-2 (Contact)		± 30	
Operating Temperature Range	TJ	-55 to +125	$^\circ\text{C}$
Storage Temperature Range	Tstg	-55 to +150	$^\circ\text{C}$

Electrical Characteristics ($T_A=25^\circ\text{C}$ unless otherwise specified)

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Reverse Working Voltage	V_{RWM}				5	V
Breakdown Voltage	V_{BR}	$I_T = 1\text{mA}$	6.0		8.5	V
Reverse Leakage Current	I_R	$V_{RWM} = 5\text{V}$			0.2	μA
Clamping Voltage	V_C	$I_{PP} = 8\text{A}$ (8 x 20 μs pulse)			12	V
Junction Capacitance	C_J	$V_R = 0\text{V}$, $f = 1\text{MHz}$			70	pF

Portion Electronics Parameter

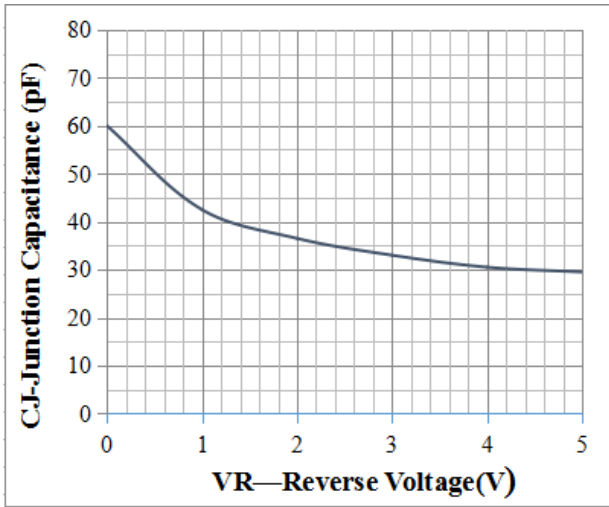
Symbol	Parameter
I_T	Test Current
I_{PP}	Maximum Reverse Peak Pulse Current
V_C	Clamping Voltage @ I_C



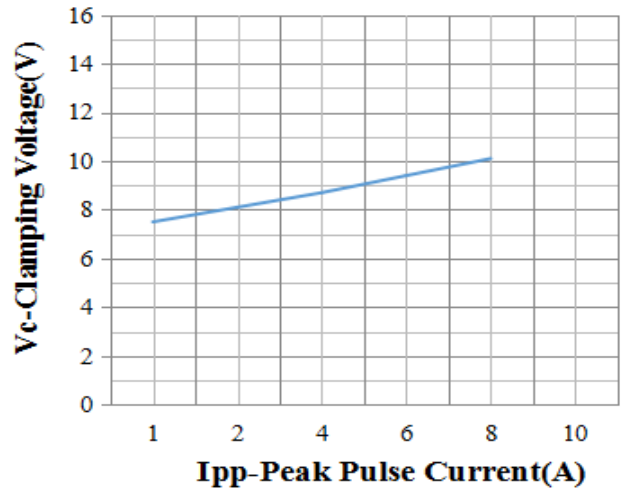


JLE05ULS9-2

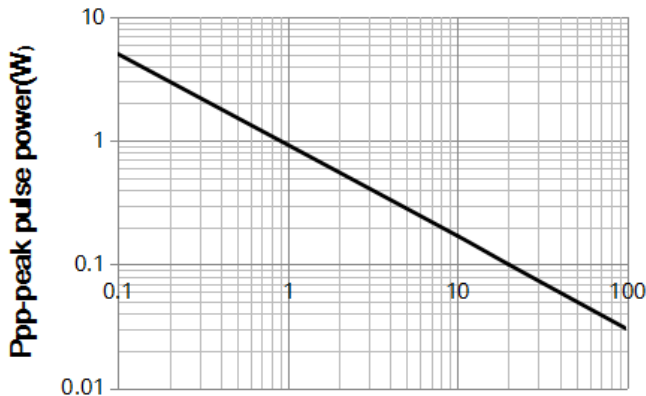
Typical Performance Characteristics ($T_A=25^\circ\text{C}$ unless otherwise Specified)



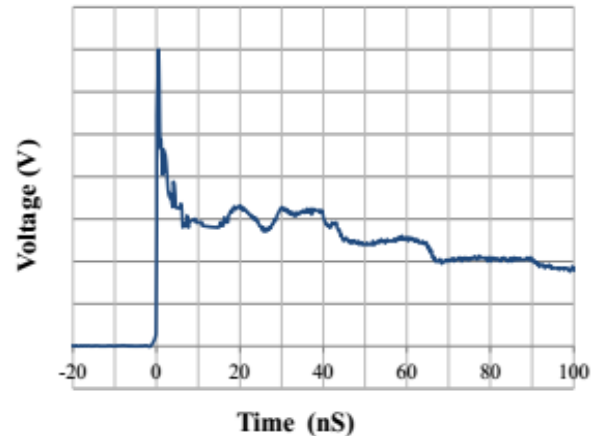
Junction Capacitance vs. Reverse Voltage



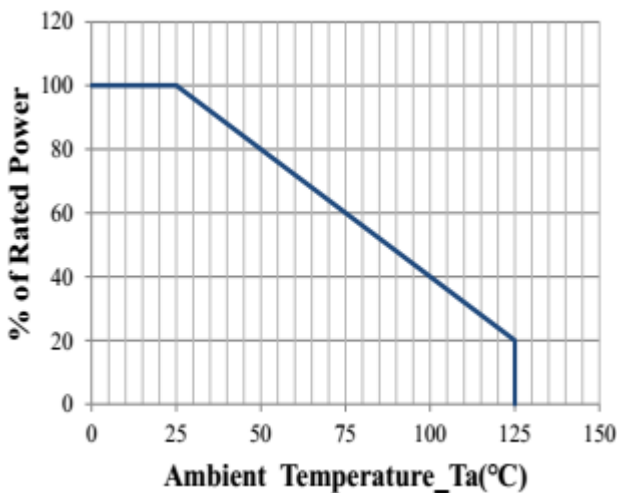
Clamping Voltage vs. Peak Pulse Current



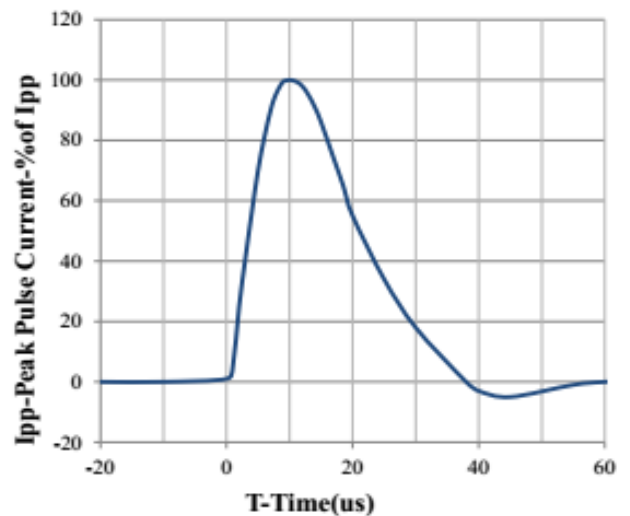
Peak Pulse Power vs. Pulse Time



IEC61000-4-2 Pulse Waveform



Power Derating Curve

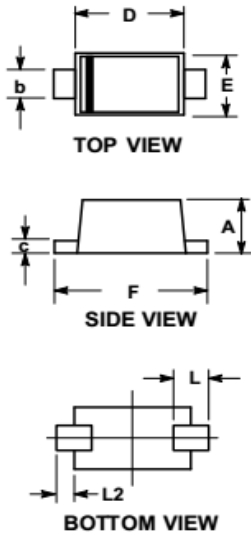


8 X 20us Pulse Waveform



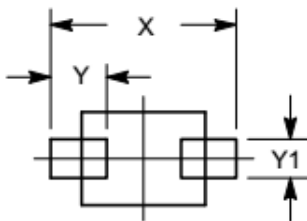
JLE05ULS9-2

SOD-923 Package Outline Drawing (Dimensions in millimeters)



SYM	DIMENSIONS					
	MILLIMETERS			INCHES		
	MIN	NOM	MAX	MIN	NOM	MAX
A	0.39	0.42	0.45	0.016	0.017	0.018
b	0.15	0.20	0.25	0.006	0.008	0.010
c	0.07	0.12	0.17	0.003	0.005	0.007
D	0.75	0.80	0.85	0.030	0.032	0.034
E	0.55	0.60	0.65	0.022	0.024	0.026
F	0.95	1.00	1.05	0.038	0.040	0.042
L	0.19 REF			0.007 REF		
L2	0.05	0.10	0.15	0.002	0.004	0.006

Suggested Land Pattern



SYM	DIMENSIONS	
	MILLIMETERS	INCHES
X	1.20	0.048
Y	0.36	0.014
Y1	0.25	0.010

NOTICE

Jelan-Link reserves the right to make changes without further notice to any products here in.

Only obligations are those in the Jelan-Link Standard Terms and Conditions of Sale and in no case will Jelan-Link be liable for any incidental, indirect, or consequential damages arising from the sale, resale, use, or misuse of its products.